

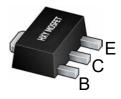
#### **Features**

• Collector Current: I<sub>C</sub>=-1.5A

 Power Dissipation of 500mw

## **Package Marking and Ordering Information**

Product ID	roduct ID Pack		Qty(PCS)	
SS8550	SOT89-3L	Y2	1000	



**SOT89-3L** 



# Maxmim Ratings (Ta=25 unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-25	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Collector Current	I <sub>c</sub>	-1.5	А
Collector Power Dissipation	P <sub>c</sub>	500	mW
Thermal Resistance From Junction To Ambient	R <sub>OJA</sub>	250	°C/W
Junction Temperature	T <sub>j</sub>	150	℃
Storage Temperature	T <sub>stg</sub>	-55∼+150	°C

## Classifiction Of hFE

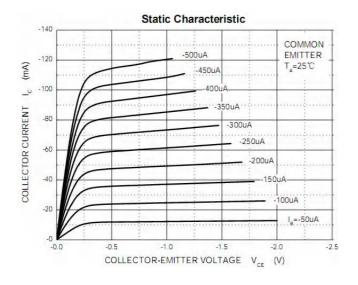
Rank	L	Н	J
Range	120–200	200–350	300–400
Marking		Y2	

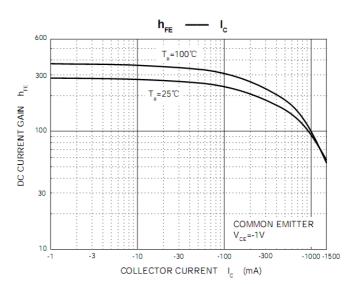


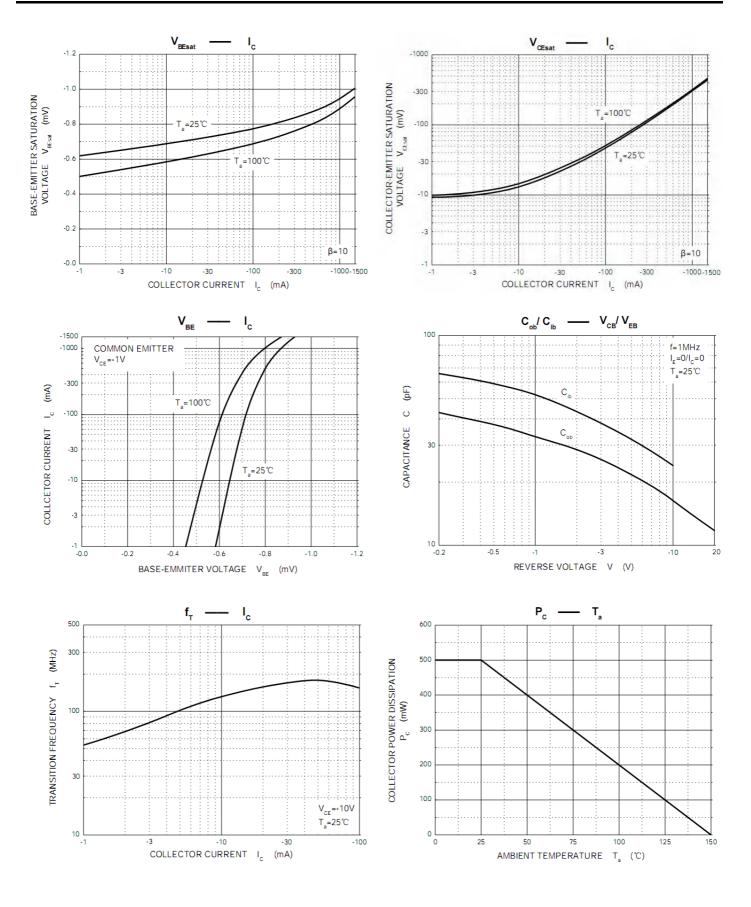
### Electrcal Charcteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = -100μA, I <sub>E</sub> =0	-40		V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = -0.1mA, I <sub>B</sub> =0	-25		V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = -100μA, I <sub>C</sub> =0	-5		V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -40 V,I <sub>E</sub> =0		-0.1	μA
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> = -20V, I <sub>B</sub> =0		-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -5V, I <sub>C</sub> =0		-0.1	μA
DC current sein	h <sub>FE(1)</sub>	V <sub>CE</sub> = -1V, I <sub>C</sub> = -100mA	85	400	
DC current gain	h <sub>FE(2)</sub>	V <sub>CE</sub> = -1V, I <sub>C</sub> = -800mA	40		
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-800mA, I <sub>B</sub> = -80mA		-0.5	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =-800mA, I <sub>B</sub> = -80mA		-1.2	V
Base-emitter on voltage	V <sub>BE(on)</sub>	Ic=-1V,V <sub>CE</sub> =-10mA		-1	V
Base-emitter positive favor voltage	$V_{BEF}$	I <sub>B</sub> =-1A		-1.55	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA	100		MHz
output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V,I <sub>E</sub> =0,f=1MHz		20	pF

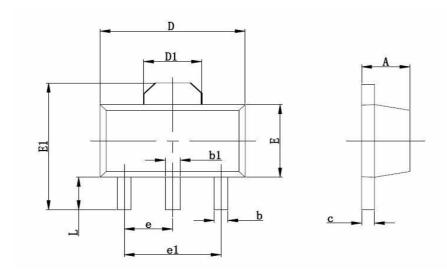
#### **Typical Characteristics**







### **SOT89-3L Package Outline Dimensions**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
Α	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
С	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF.		0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
е	1.500 TYP.		0.060 TYP.	
e1	3.000 TYP.		0.118 TYP.	
L	0.900	1.200	0.035	0.047



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